

# SD107WS

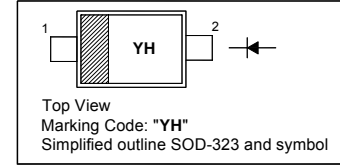
## SURFACE MOUNT SCHOTTKY BARRIER DIODE

### Features

- Low forward voltage drop

### PINNING

PIN	DESCRIPTION
1	Cathode
2	Anode

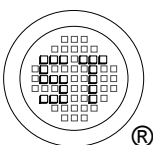


### Absolute Maximum Ratings ( $T_a = 25\text{ }^\circ\text{C}$ )

Parameter	Symbol	Value	Unit
Repetitive Peak Reverse Voltage	$V_{RRM}$	30	V
Non-Repetitive Peak Reverse Voltage	$V_{RSM}$	30	V
DC Blocking Voltage	$V_R$	30	V
Forward Continuous Current	$I_{FM}$	100	mA
Non-Repetitive Peak Forward Surge Current ( $t \leq 10\text{ ms}$ )	$I_{FSM}$	750	mA
Power Dissipation	$P_d$	250	mW
Operating and Storage Temperature Range	$T_j, T_{stg}$	- 65 to + 125	$^\circ\text{C}$

### Characteristics at $T_a = 25\text{ }^\circ\text{C}$

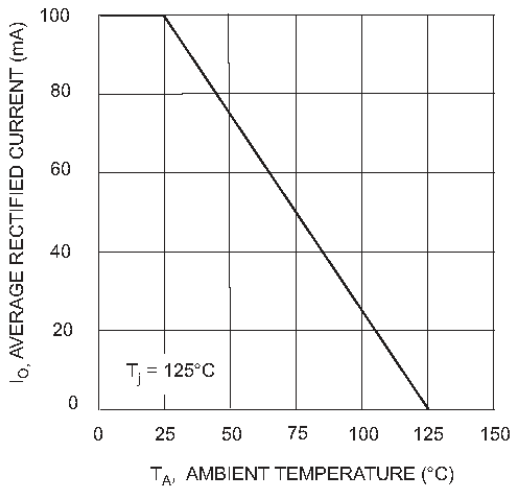
Parameter	Symbol	Min.	Max.	Unit
Forward Voltage at $I_F = 50\text{ mA}$ at $I_F = 100\text{ mA}$	$V_F$	- -	0.55 0.8	V
Reverse Breakdown Voltage at $I_R = 100\text{ }\mu\text{A}$	$V_{(BR)R}$	30	-	V
Reverse Current at $V_R = 25\text{ V}$	$I_R$	-	1	$\mu\text{A}$



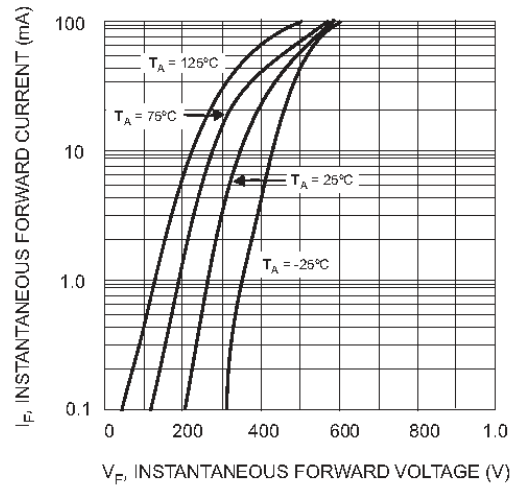
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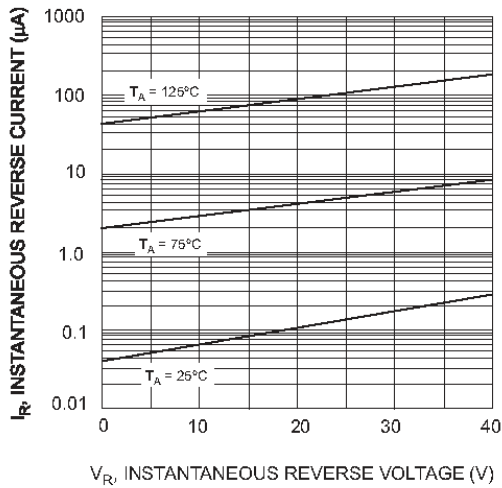
Dated : 29/11/2007



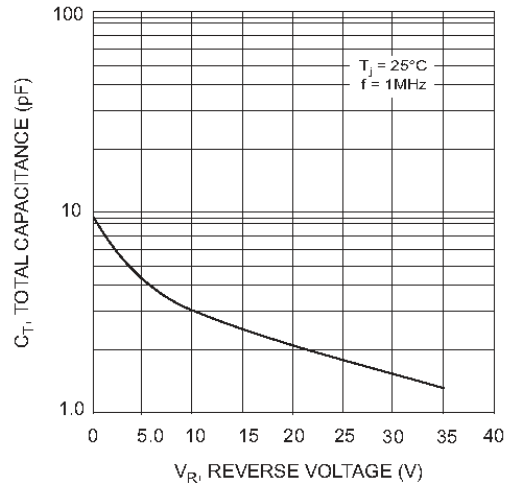
$T_A$ , AMBIENT TEMPERATURE (°C)  
Fig. 1 Forward Current Derating Curve



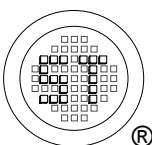
$V_F$ , INSTANTANEOUS FORWARD VOLTAGE (V)  
Fig. 2 Typical Forward Characteristics



$V_R$ , INSTANTANEOUS REVERSE VOLTAGE (V)  
Fig. 3 Typical Reverse Characteristics



$V_R$ , REVERSE VOLTAGE (V)  
Fig. 4 Total Capacitance vs. Reverse Voltage



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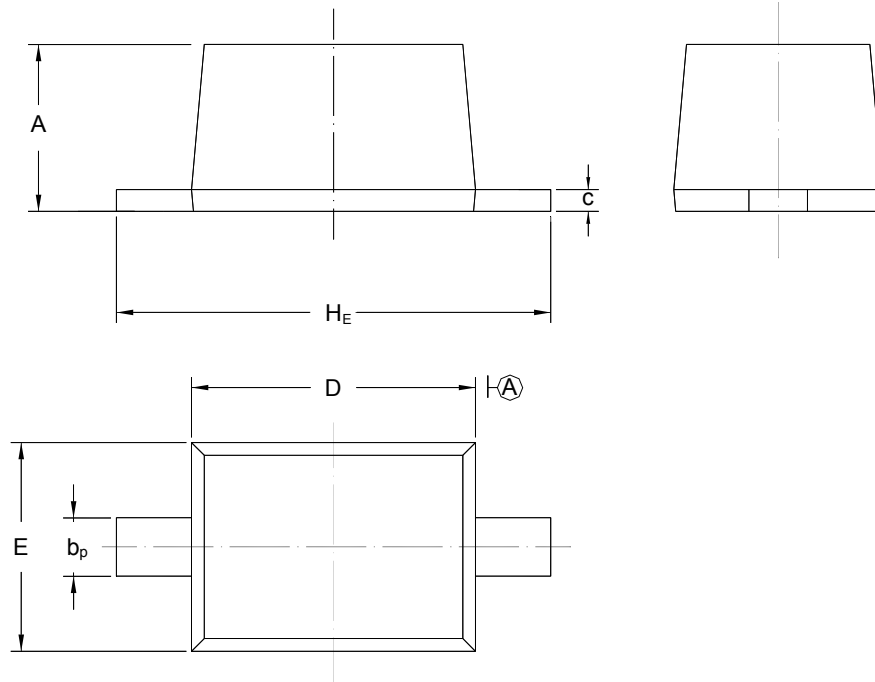


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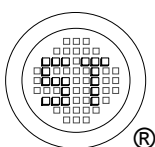
## PACKAGE OUTLINE

Plastic surface mounted package; 2 leads

SOD-323



UNIT	A	b <sub>p</sub>	C	D	E	H <sub>E</sub>
mm	1.10 0.80	0.40 0.25	0.15 0.10	1.80 1.60	1.35 1.15	2.80 2.30



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